

Data sheet acquired from Harris Semiconductor SCHS060

CMOS Dual 2-Wide 2-Input AND-OR-INVERT Gate

High-Voltage Types (20-Volt Rating)

■ CD4085 contains a pair of AND-OR-INVERT gates, each consisting of two 2-input AND gates driving a 3-input NOR gate. Individual inhibit controls are provided for both A-O-I gates.

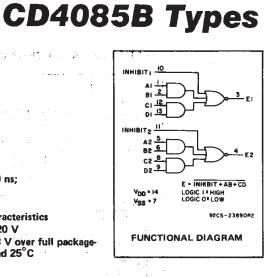
The CD4085B types are supplied in 14-lead dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (Esuffix), and in chip form (H suffix).

Features:

- Medium-speed operation tpHL = 90 ns; tp_H ≈ 125 ns (typ.) at 10 V
- Individual inhibit controls
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full packagetemperature range; 100 nA at 18 V and 25°C
- Noise margin (over full packagetemperature range):

1 V at V_{DD} = 5 V 2 V at V_{DD} = 10 V 2.5 V at V_{DD} = 15 V ■ 5-V, 10-V, and 15-V parametric ratings

- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



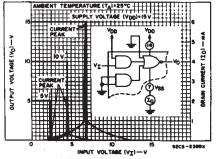


Fig. 1 - Typical voltage and current transfer characteristics.

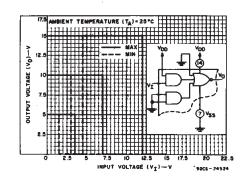


Fig. 2 — Min. and max. voltage transfer characteristics.

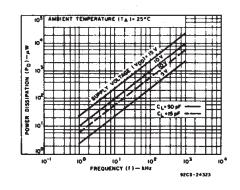
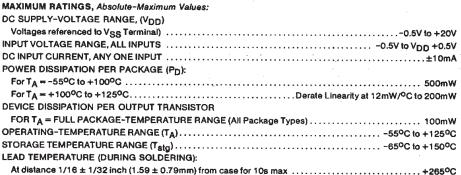


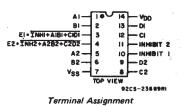
Fig. 3 — Typical power dissipation vs. frequency.



RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIA	UNITS	
<u> </u>	Min.	Max.	I
Supply Voltage Range (For TA=Full Package Temperature Range)	3	18	V



CD4085B Types

STATIC ELECTRICAL CHARACTERISTICS

							*,			10 3	. 14
CHARAC- TERISTIC		CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)					PC)	UNITS
TENISTIC	Vo	VIN	V_{DD}						+25		
	(V)	(V)	(V)	–55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent		0,5	5	1	1	30	30	_	0.02	1	
Device		0,10	10	2	2	60	60		0.02	2	μА
Current		0,15	15	4	4	120	120		0.02	4	, m
IDD Max.	-	0,20	20	20	20	600	600	-	0.04	20	
Output Low					11 11					7	
(Sink)	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1		1.14
Current,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	} •
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	mA
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	111/4
(Source)	2.5	0,5	5	2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	_	
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Volt-											
age:	_	0,5	5		0.05				0	0.05	
Low-Level,		0,10	10	0.05			_	0	0.05		
VOL Max.	_	0,15	15	0.05			_	0	0.05	v	
Output Volt-						-					ľ
age:	_	0,5	5		4.95			4.95	5		
High Level,		0,10	10		9.9	95		9.95	10	_	
VOH Min.	_	0,15	15		14.95			14.95	15	-	
Input Low	0.5,4.5	_	5.		1.	5		_		1.5	
Voltage,	1,9	_	10				_	-	3		
VIL Max.	1.5,13.5	-	15					_	4		
Input High	0.5,4.5	_	5	3.5			3.5		-	ľ	
Voltage,	1,9		10	7 11			7		_]	
V _{IH} Min.	1.5,13.5	-	15				11	-	-		
Input Current, I _{IN} Max.	_	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ

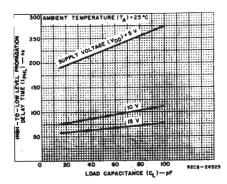


Fig. 4 - Typical data high-to-low level propagation delay time vs. load capacitance.

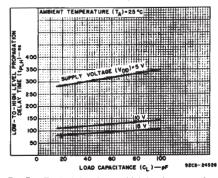


Fig. 5 — Typical data low-to-high level propagation delay time vs. load capacitance.

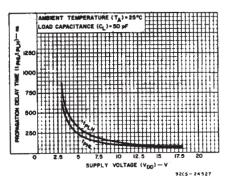


Fig. 6 — Typical data propagation delay time vs. supply voltage.

CD4085B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T $_A$ = 25°C; Input t_, t_f = 20 ns, C $_L$ = 50 pF, R $_L$ = 200 K Ω

		CONDITIONS	LIMITS			
CHARACTERISTIC		V _{DD}	Тур.	Max.	UNITS	
Proposition Delay Time (Date)		5	225	450		
Propagation Delay Time (Data): High-to-Low Level,	^t PHL	10	90	180	ns	
		15	65	130		
	^t PLH	5	310	620	ns	
Low-to-High Level,		10	125	250		
		15	90	180		
Propagation Delay Time (Inhibit		5	150	300	ns	
	tPHL	10	60	120		
riigii to Lott Lotti,		15	40	80		
	^t PLH	5	250	500		
Low-to-High Level,		10	100	200	ns	
		15	70	140		
Transition Time,	^t THL ^{, t} TLH	5	100	200		
		10	50	100	ns	
		15	40	80		
Input Capacitance,	CIN	Any Input	5	7.5	pF	

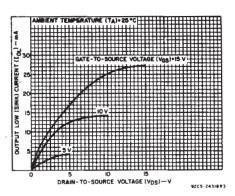


Fig. 7 — Typical output low (sink) current characteristics.

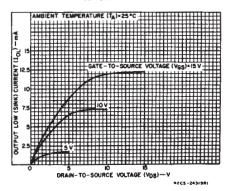


Fig. 8 – Minimum output low (sink) current characteristics.

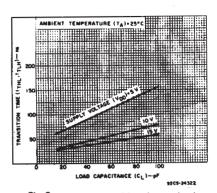


Fig. 9 — Typical transition time vs. load capacitance.

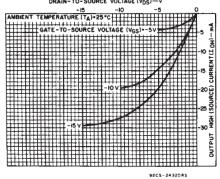


Fig. 10 - Typical output high (source) current characteristics.

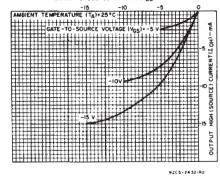


Fig. 11 — Minimum output high (source) current characteristics.

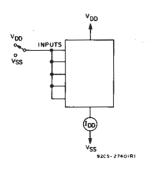


Fig. 12 - Quiescent device current test circuit.

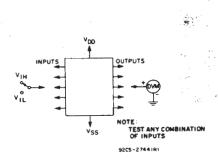


Fig. 13 - Input voltage test circuit.

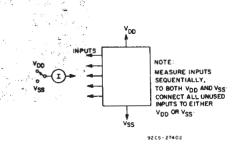


Fig. 14 - Input current test circuit.

CD4085B Types

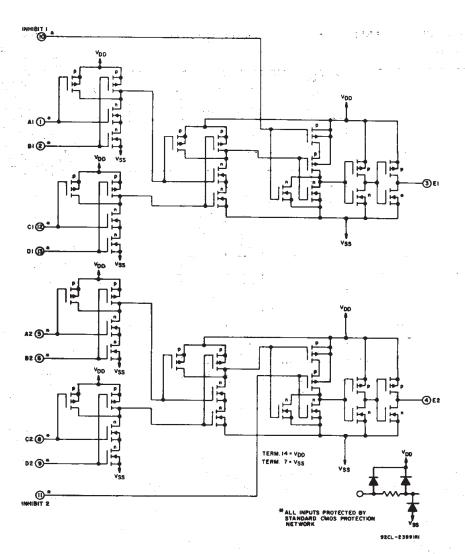
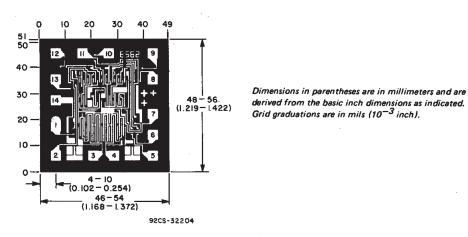


Fig. 15 - CD4085'schematic diagram.



Dimensions and Pad Layout for CD40858H.

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